

September 1998

#### **54ACTQ32**

# **Quiet Series Quad 2-Input OR Gate**

### **General Description**

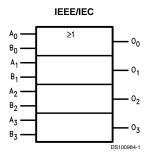
The 'ACTQ32 contains four, 2-input OR gates and utilizes NSC Quiet Series technology to guarantee quiet output switching and improved dynamic threshold performance. FACT Quiet Series™ features GTO™ output control and undershoot corrector in addition to a split ground bus for superior ACMOS performance.

- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Improved latch-up immunity
- Outputs source/sink 24 mA
- 'ACTQ32 has TTL-compatible inputs
- Standard Microcircuit Drawing (SMD) 5962-8973601

#### **Features**

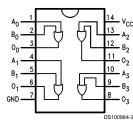
■ I<sub>CC</sub> reduced by 50%

#### **Logic Symbol**



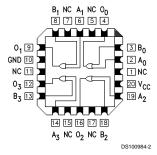
#### Connection Diagrams

#### Pin Assignment for DIP and Flatpak



| Pin Names                       | Description |
|---------------------------------|-------------|
| A <sub>n</sub> , B <sub>n</sub> | Inputs      |
| O <sub>n</sub>                  | Outputs     |

#### Pin Assignment for LCC



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#### **Absolute Maximum Ratings** (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

DC Output Voltage ( $V_O$ ) -0.5V to  $V_{CC}$  + 0.5V DC Output Source

or Sink Current (I<sub>O</sub>)
DC V<sub>CC</sub> or Ground Current

per Output Pin ( $I_{CC}$  or  $I_{GND}$ )  $\pm 50$  mA Storage Temperature ( $T_{STG}$ )  $-65^{\circ}$ C to  $+150^{\circ}$ C

Junction Temperature ( $T_J$ ) CDIP 175°C

# Recommended Operating Conditions

 $\begin{array}{lll} \text{Supply Voltage ($V_{CC}$)} \\ \text{'ACTQ} & \text{4.5V to 5.5V} \\ \text{Input Voltage ($V_{O}$)} & \text{0V to $V_{CC}$} \\ \text{Output Voltage ($V_{O}$)} & \text{0V to $V_{CC}$} \\ \end{array}$ 

Operating Temperature (T<sub>A</sub>)

54ACTQ -55°C to +125°C

Minimum Input Edge Rate ( $\Delta V/\Delta t$ )

'ACTQ Devices V<sub>IN</sub> from 0.8V to 2.0V

 $V_{CC}$  @ 4.5V, 5.5V 125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. National does not recommend operation of FACT<sup>TM</sup> circuits outside databook specifications.

#### DC Characteristics for 'ACTQ Family Devices

|                  |                         |                 | 54ACTQ            |       |                                     |
|------------------|-------------------------|-----------------|-------------------|-------|-------------------------------------|
| Symbol           | Parameter               | V <sub>cc</sub> | T <sub>A</sub> =  | Units | Conditions                          |
|                  |                         | (V)             | -55°C to +125°C   |       |                                     |
|                  |                         |                 | Guaranteed Limits |       |                                     |
| V <sub>IH</sub>  | Minimum High Level      | 4.5             | 2.0               | V     | V <sub>OUT</sub> = 0.1V             |
|                  | Input Voltage           | 5.5             | 2.0               |       | or V <sub>CC</sub> – 0.1V           |
| V <sub>IL</sub>  | Maximum Low Level       | 4.5             | 0.8               | V     | V <sub>OUT</sub> = 0.1V             |
|                  | Input Voltage           | 5.5             | 0.8               |       | or V <sub>CC</sub> – 0.1V           |
| V <sub>OH</sub>  | Minimum High Level      | 4.5             | 4.4               | V     | I <sub>OUT</sub> = -50 μA           |
|                  | Output Voltage          | 5.5             | 5.4               |       |                                     |
|                  |                         |                 |                   |       | (Note 2)                            |
|                  |                         |                 |                   |       | $V_{IN} = V_{IL} \text{or } V_{IH}$ |
|                  |                         | 4.5             | 3.70              | V     | $I_{OH} = -24 \text{ mA}$           |
|                  |                         | 5.5             | 4.70              |       | $I_{OH} = -24 \text{ mA}$           |
| V <sub>OL</sub>  | Maximum Low Level       | 4.5             | 0.1               | V     | I <sub>OUT</sub> = 50 μA            |
|                  | Output Voltage          | 5.5             | 0.1               |       |                                     |
|                  |                         |                 |                   |       | (Note 2)                            |
|                  |                         |                 |                   |       | $V_{IN} = V_{IL} \text{or } V_{IH}$ |
|                  |                         | 4.5             | 0.50              | V     | I <sub>OL</sub> = 24 mA             |
|                  |                         | 5.5             | 0.50              |       | I <sub>OL</sub> = 24 mA             |
| I <sub>IN</sub>  | Maximum Input           | 5.5             | ±1.0              | μA    | $V_I = V_{CC}$ , GND                |
|                  | Leakage Current         |                 |                   |       |                                     |
| I <sub>CCT</sub> | Maximum                 | 5.5             | 1.6               | mA    | $V_I = V_{CC} - 2.1V$               |
|                  | I <sub>CC</sub> /Input  |                 |                   |       |                                     |
| I <sub>OLD</sub> | Minimum Dynamic         | 5.5             | 50                | mA    | V <sub>OLD</sub> = 1.65V Max        |
| I <sub>OHD</sub> | Output Current (Note 3) | 5.5             | -50               | mA    | V <sub>OHD</sub> = 3.85V Min        |
| I <sub>cc</sub>  | Maximum Quiescent       | 5.5             | 80.0              | μA    | V <sub>IN</sub> = V <sub>CC</sub>   |
|                  | Supply Current          |                 |                   |       | or GND (Note 3)                     |

±50 mA

Note 2: All outputs loaded; thresholds on input associated with output under test.

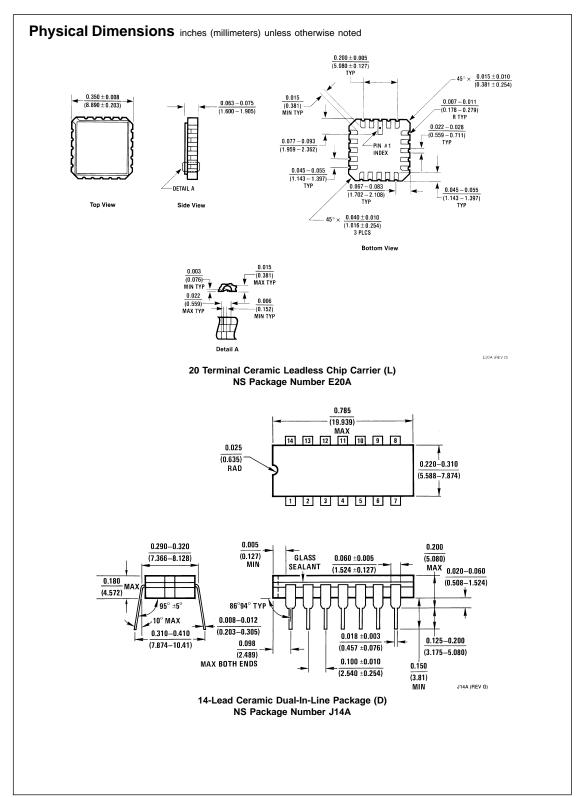
Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

#### **AC Electrical Characteristics** 54ACTQ $v_{cc}$ $T_A = -55^{\circ}C$ Fig. Symbol (V) to +125°C Units No. Parameter (Note 4) $C_L = 50 pF$ Min Max Propagation Delay 5.0 7.5 1.5 ns $t_{PLH}$ 7.5 Propagation Delay 5.0 1.5 ns $t_{\mathsf{PHL}}$

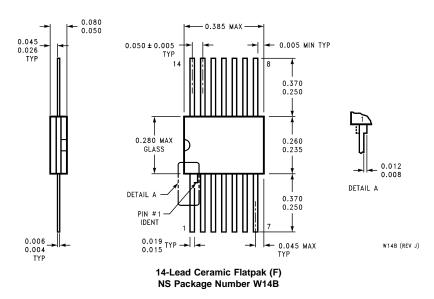
Note 4: Voltage Range 5.0 is 5.0V ±0.5V

## Capacitance

| Symbol          | Parameter         | Max  | Units | Conditions             |
|-----------------|-------------------|------|-------|------------------------|
| C <sub>IN</sub> | Input Capacitance | 10.0 | pF    | V <sub>CC</sub> = OPEN |
| C <sub>PD</sub> | Power Dissipation | 72.0 | pF    | V <sub>CC</sub> = 5.0V |
|                 | Capacitance       |      |       |                        |



#### Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



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- 2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.



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